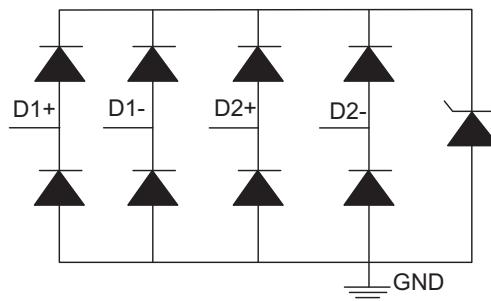


Illustration

TPD 4E1U06 is an electrostatic discharge (ESD) protection diode based on a four-channel one-way transient voltage suppressor (TVS), with ultra-low capacitance. The ESD shock dissipation value of this device is higher than the highest level stipulated by the IEC 61000-4 -2 international standard. Its 0.8 pF line capacitors make it widely applicable to output current sensing resistors and operational amplifiers for various applications. Typical application areas include HDMI, USB 2.0, MHL, and DisplayPort.



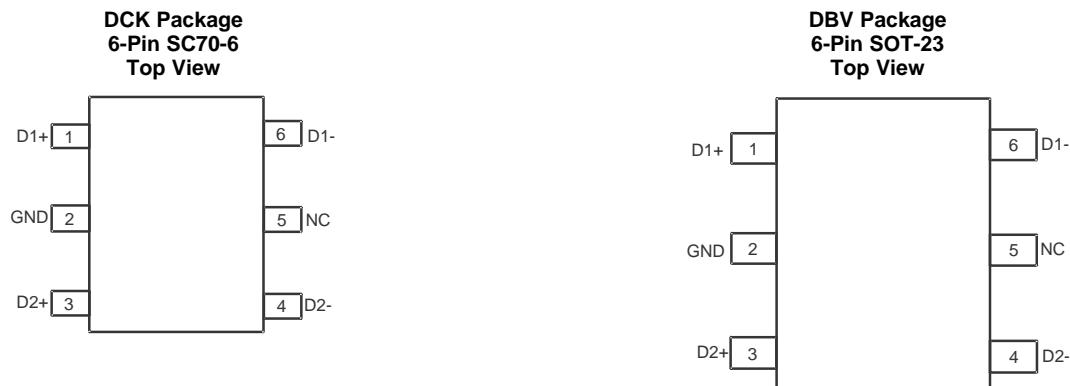
Features

- IEC 61000-4-2 4 ESD protection
 - $\pm 15\text{kV}$, with contact discharge
 - $\pm 15\text{kV}$, air-gap discharge
- IEC61000-4-4 Transient discharge (EFT) protection
 - 80A (5/50ns)
- IEC61000-4-5 Surge protection
 - 3A (8/20 μs)
- IO capacitance: 0.8 pF (typical value)
- DC breakdown voltage: 6.5V (minimum)
- Ultra-low leakage current: 10 nA (max.)
- Low ESD clamp voltage
- Industrial temperature range: -40°C to + 125°C Small,
- easy-to-wire DCK and DBV packages

Application

- USB 2.0
- Ethernet
- HD Multimedia interface (HDMI) control line Mobile
- industry processor interface (MIPI) bus Low Pressure
- Differential signaling (LVDS)

Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
D1+	1	I/O	ESD protected channel. Connect to data line as close to the connector as possible
D1-	6		
D2-	4		
D2+	3		
GND	2	GND	Ground. Connect to ground
NC	5	I/O	No connect. Can be left floating, grounded, or connected to VCC

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
	IEC 61000-4-4 EFT protection (5/50 ns)		80	A
I _{PP}	IEC 61000-4-5 surge protection (8/20 µs) peak pulse current		3	A
P _{PP}	IEC 61000-4-5 surge protection (8/20 µs) peak pulse power		45	W
	Operating temperature	-40	125	°C
T _{stg}	Storage temperature	-65	115	°C

ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±4000
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

ESD Ratings—IEC Specification

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	IEC 61000-4-2 contact ESD	±15000
		IEC 61000-4-2 air-gap ESD	

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{IO}	Input pin voltage	0	5.5	V
T _A	Operating free-air temperature	-40	125	°C

Thermal Information

THERMAL METRIC ⁽¹⁾	TPD4E1U06		UNIT
	DBV (SOT-23)	DCK (SC-70)	
	6 PINS	6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	224.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	166.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	68.4	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	57.3	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	67.9	°C/W

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{RWM} Reverse stand-off voltage	$I_{IO} = 10 \mu A$			5.5	V
V_{CLAMP} Clamp voltage with ESD strike	$I_{PP} = 1 A$, $t_p = 8/20 \mu s$, from I/O to GND ⁽¹⁾		11		V
	$I_{PP} = 3 A$, $t_p = 8/20 \mu s$, from I/O to GND ⁽¹⁾		15		V
R_{DYN} Dynamic resistance	Pin x to GND pin ⁽²⁾		1.0		Ω
	GND to pin x		0.6		
C_L Line capacitance	$f = 1 MHz$, $V_{BIAS} = 2.5 V$, $25^\circ C$		0.8	1	pF
C_{CROSS} Channel to channel input capacitance	Pin 2 = 0 V, $f = 1 MHz$, $V_{BIAS} = 2.5 V$, between channel pins	DCK package	0.006	0.015	pF
		DBV package	0.01	0.025	
$\Delta C_{IO-TO-GND}$ Variation of channel input capacitance	Pin 2 = 0 V, $f = 1 MHz$, $V_{BIAS} = 2.5 V$, channel_x pin to ground – channel_y pin to ground		0.025	0.07	pF
V_{BR} Break-down voltage, IO to GND	$I_{IO} = 1 mA$		6.5	8.5	V
I_{LEAK} Leakage current	$V_{IO} = 2.5 V$		1	10	nA

(1) Non-repetitive current pulse 8/20 μs exponentially decaying waveform according to IEC61000-4-5.

(2) Extraction of R_{DYN} using least squares fit of TLP characteristics between $I = 10 A$ and $I = 20 A$.

Typical Characteristics

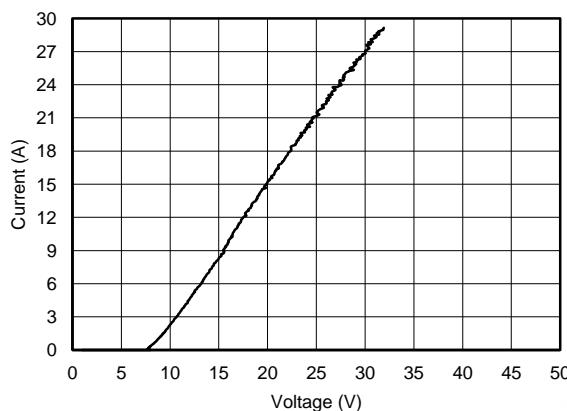


Figure 1. TLP, Data to GND

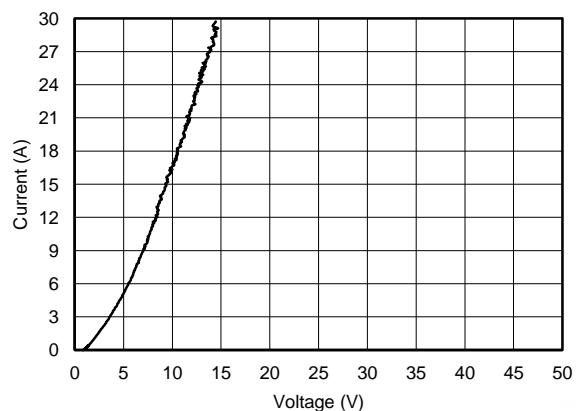


Figure 2. TLP, GND to Data

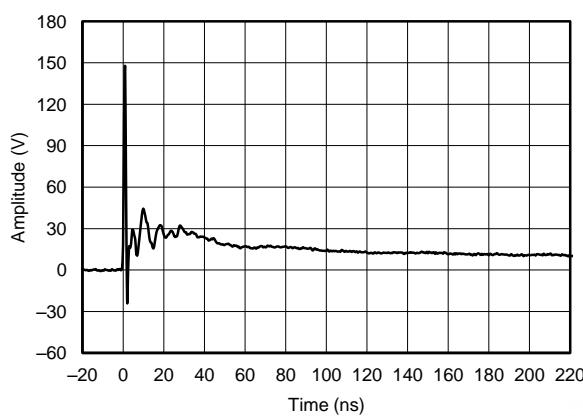


Figure 3. IEC 61000-4-2 Clamping Voltage, 8-kV Contact

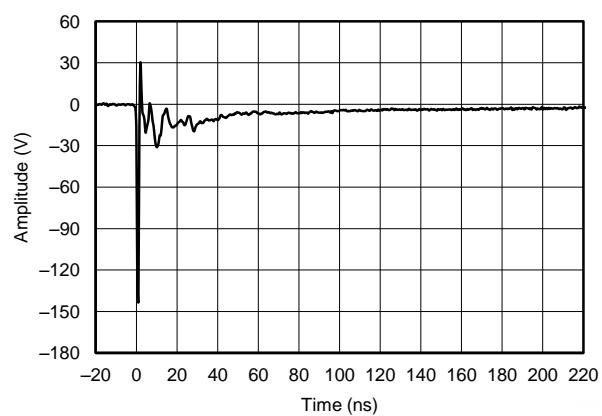


Figure 4. IEC 61000-4-2 Clamping Voltage, -8-kV Contact

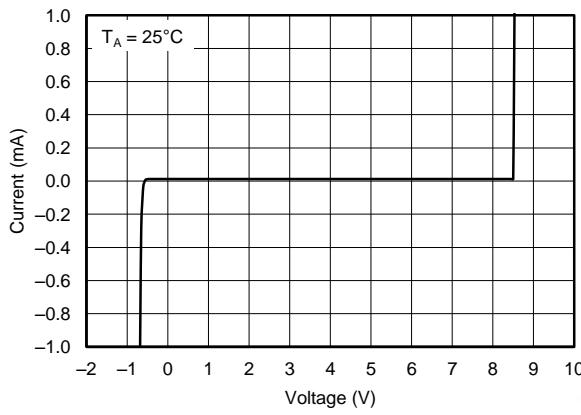


Figure 5. Diode Curve

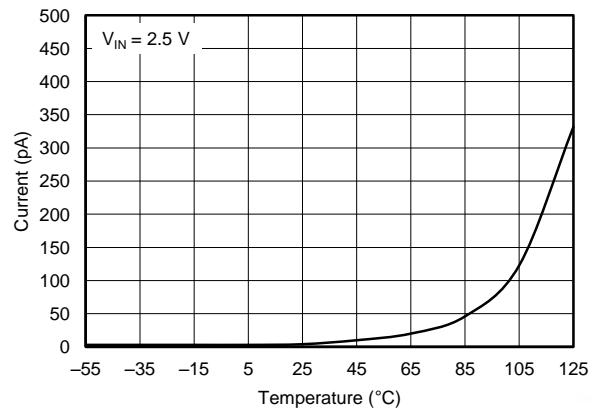
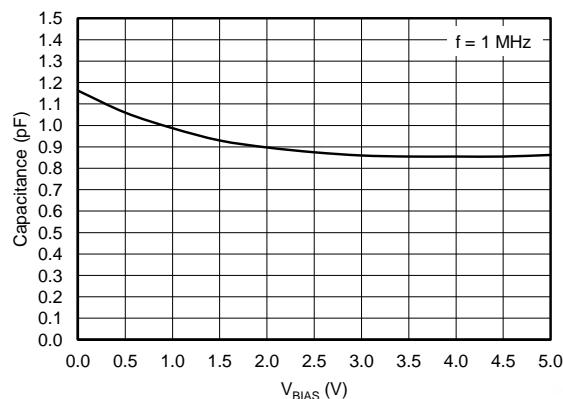
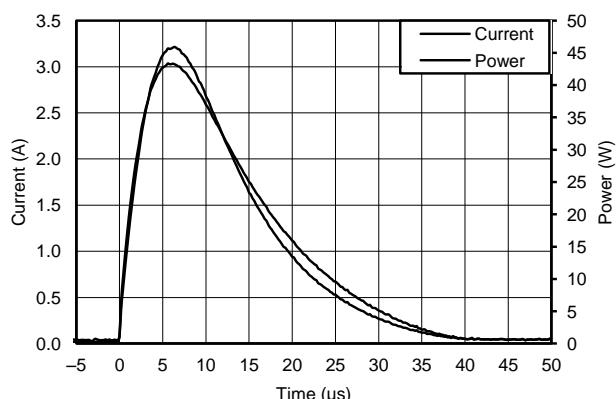


Figure 6. I_{LEAK} vs Temperature

Typical Characteristics (continued)**Figure 7. Capacitance Across V_{BIAS}** **Figure 8. Surge Curve ($t_p = 8/20 \mu\text{s}$), Pin IO to GND**

Detailed Description

Overview

The TPD4E1U06 is a quad channel unidirectional TVS ESD protection diode with ultra low capacitance. This device can dissipate ESD strikes above the maximum level specified by the IEC 61000-4-2 international standard. Typical application areas include HDMI, USB2.0, MHL, and DisplayPort. Its 0.8-pF line capacitance makes it suitable for a wide range of applications.

Functional Block Diagram

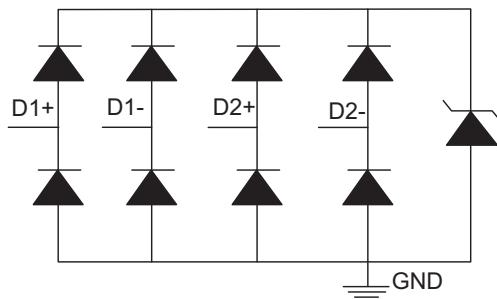


Figure 9. Circuit Schematic Diagram

Feature Description

IEC 61000-4-2 Level 4 ESD Protection

The I/O pins can withstand ESD events up to $\pm 15\text{-kV}$ contact and air. An ESD/surge clamp diverts the current to ground.

IEC 61000-4-5 Surge Protection

The IO pins can withstand surge events up to 3 A and 45 W (8/20- μs waveform). An ESD-surge clamp diverts this current to ground.

IEC 61000-4-4 EFT Protection

The IO pins can withstand an electrical fast transient burst of up to 80 A (5/50-ns waveform, 4 kV with 50- Ω impedance). An ESD-surge clamp diverts the current to ground.

IO Capacitance

The capacitance between each I/O pin to ground is 0.8 pF.

DC Breakdown Voltage

The DC breakdown voltage of each I/O pin is a minimum of 6.5 V. This ensures that sensitive equipment is protected from surges above the reverse standoff voltage of 5.5 V.

Ultra Low Leakage Current

The I/O pins feature an ultra-low leakage current of 10 nA (Maximum) with a bias of 2.5 V.

Low ESD Clamping Voltage

The I/O pins feature an ESD clamp that is capable of clamping the voltage to 11 V ($I_{PP} = 1\text{ A}$).

Industrial Temperature Range

This device features an industrial operating range of -40°C to $+125^\circ\text{C}$.

Typical Application (continued)

Design Requirements

Given the USB 2.0 application, the parameters in Table 1 are known.

Table 1. Design Parameters

DESIGN PARAMETER	VALUE
Signal range on pins 1, 3, 4, or 6	0 V to 5 V
Operating frequency	240 MHz

Detailed Design Procedure

Signal Range on Pins 1, 3, 4, or 6

The TPD4E1U06 has 4 identical protection channels for signal lines. The symmetry of the device provides flexibility when selecting which of the 4 I/O channels protect which signal lines. Any I/O supports a signal range of 0 to 5.5 V.

Operating Frequency

The TPD4E1U06 has a capacitance of 0.8 pF (typical), supporting USB 2.0 data rates.

Application Curve

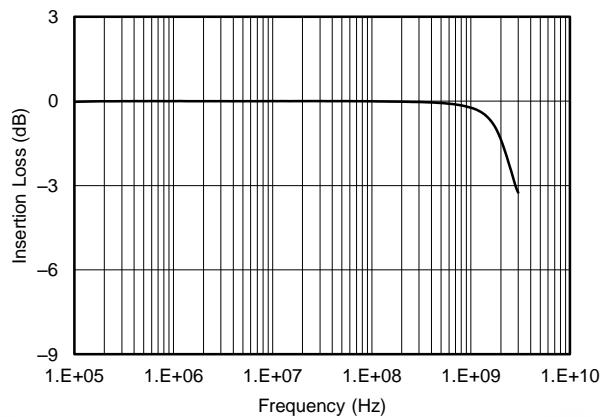
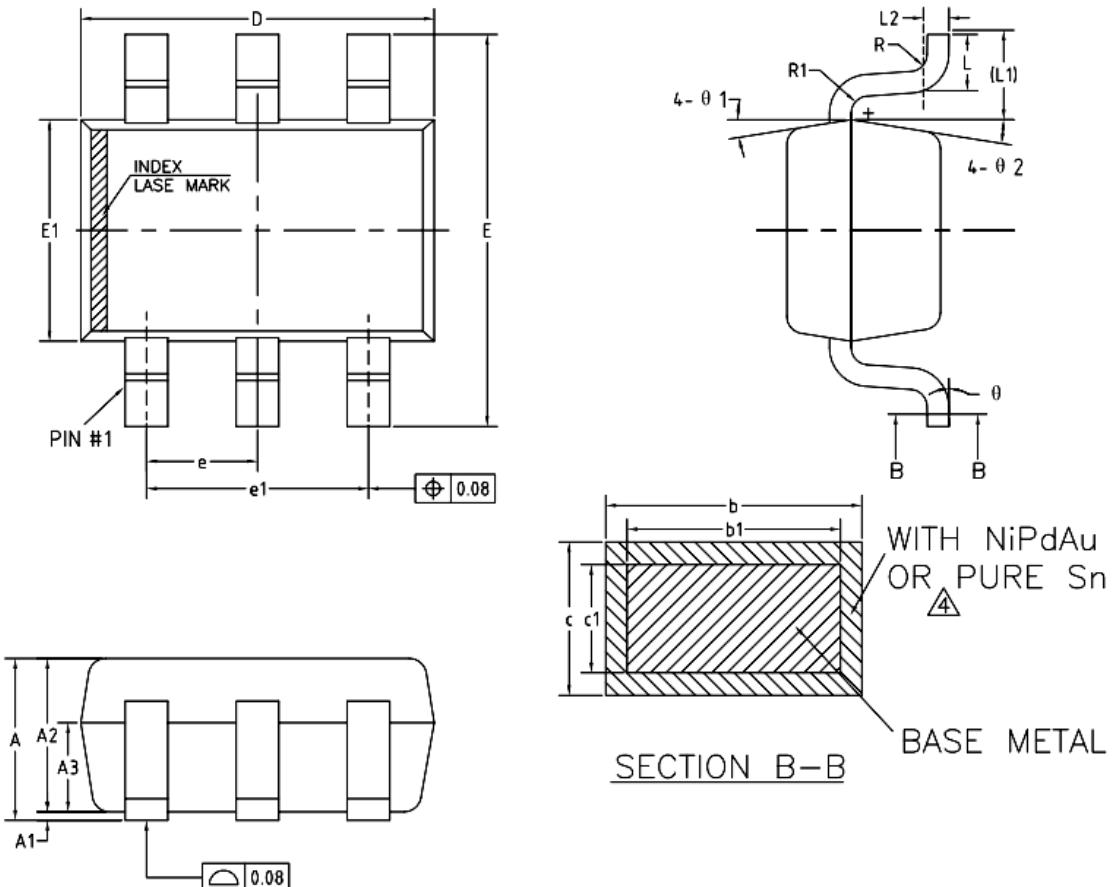


Figure 11. Insertion Loss Graph

SOT23-6

SC70-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
A	0.85	—	1.05	
A1	0	—	0.10	
A2	0.80	0.90	1.00	
A3	0.47	0.52	0.57	
b	NiPdAu PURE Sn	0.22 0.23	— —	0.29 0.33
b1	0.22	0.25	0.28	
c	NiPdAu PURE Sn	0.115 0.12	— —	0.15 0.18
c1	0.115	0.13	0.14	
D	2.02	2.07	2.12	
E	2.20	2.30	2.40	
E1	1.25	1.30	1.35	
e	0.60	0.65	0.70	
e1	1.20	1.30	1.40	
L	0.28	0.33	0.38	
L1	0.50REF			
L2	0.15BSC			
R	0.10	—	—	
R1	0.10	—	0.25	
θ	0°	—	8°	
θ_1	6°	9°	12°	
θ_2	6°	9°	12°	

Marking**Ordering information**

Order code	Package	Base qty	Delivery mode
UMW TPD4E1U06DBVR	SOT23-6	3000	Tape and reel
UMW TPD4E1U06DCKR	SC70-6	3000	Tape and reel

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[P6KE13CA](#) [P6KE43CA](#) [P6KE6.8CA](#) [P6KE8.2](#) [P6SMBJ20CA](#) [JANTX1N6072A](#) [SR2835ESKG](#) [SA90CA](#)